NSN 5962-01-048-1301

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View Online at https://aerobasegroup.com/nsn/5962-01-048-1301
Body Length:
Between 0.710 inches and 0.730 inches
Body Width:
Between 0.375 inches and 0.385 inches
Body Height:
Between 0.052 inches and 0.076 inches
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Aircraft model f-14
Features Provided:
Monolithic and hermetically sealed and negative outputs and positive outputs and programmable and programmed and w/enable and
asynchronous and synchronous and w/disable and w/decoded output and w/register output and w/storage
Inclosure Material:
Glass and metal
Inclosure Configuration:
Flat pack
Output Logic Form:
P-type metal oxide-semiconductor logic
Input Circuit Pattern:
18 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
5.25 volts power source
Time Rating Per Chacteristic:
250.00 nanoseconds propagation delay time, low to high level output
Memory Device Type:
Rom
Memory Capacity:
Unknown
Test Data Document:
03640-6088465 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
28 flat leads
Shelf Life:
N/a

Demilitarization: Yes - demil/mli

Unit Of Measure:

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